Infineon Technologies - MB90352ESPMC-GS-137E1 Datasheet

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	F²MC-16LX
Core Size	16-Bit
Speed	24MHz
Connectivity	CANbus, EBI/EMI, I²C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, WDT
Number of I/O	51
Program Memory Size	128KB (128K x 8)
Program Memory Type	Mask ROM
EEPROM Size	-
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	3.5V ~ 5.5V
Data Converters	A/D 15x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb90352espmc-gs-137e1

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Parameter \ Part Number	MB90F356E MB90F357E	MB90F356TE MB90F357TE	MB90F356ES MB90F357ES	MB90F356TES MB90F357TES
16-bit input capture	6 channels			
	Retains 16-bit free-run timer value by (rising edge, falling edge or rising & falling edge), signals an interrupt.			
8/16-bit programmable pulse generator	6 channels (16-bit)/10 channels (8-bit) 8-bit reload counters × 12 8-bit reload registers for L pulse width×12 8-bit reload registers for H pulse width×12			
	Supports 8-bit and 16-bit operation modes. A pair of 8-bit reload counters can be configured as one 16-bit reload counter or as 8-bit prescaler + 8-bit reload counter. Operation clock frequency : fsys, fsys/2^1, fsys/2^2, fsys/2^3, fsys/2^4 or 128 μs@fosc = 4 MHz (fsys = Machine clock frequency, fosc = Oscillation clock frequency)			
CAN interface	1 channel			
	Conforms to CAN Specification Version 2.0 Part A and B. Automatic re-transmission in case of error Automatic transmission responding to Remote Frame Prioritized 16 message buffers for data and ID Supports multiple messages. Flexible configuration of acceptance filtering : Full bit compare/Full bit mask/Two partial bit masks Supports up to 1 Mbps.			
External interrupt	8 channels			
	Can be used rising edge, falling edge, starting up by H/L level input, external interrupt, extended intelligent I/O services (EI^{2}OS) and DMA.			
D/A converter	—			
I/O ports	Virtually all external pins can be used as general purpose I/O port. All push-pull outputs Bit-wise settable as input/output or peripheral module signal Settable as CMOS schmitt trigger/ automotive inputs TTL input level settable for external bus (only for external bus pin)			
Flash memory	Supports automatic programming, Embedded Algorithm Write/Erase/Erase-Suspend/Resume commands A flag indicating completion of the algorithm Number of erase cycles : 10000 times Data retention time : 20 years Boot block configuration Erase can be performed on each block. Block protection with external programming voltage Flash Security Feature for protecting the content of the Flash (MB90F357x only)			
Corresponding EVA name	MB90V340E-104		MB90V340E-103	

* : It is setting of Jumper switch (TOOL VCC) when Emulator (MB2147-01) is used.
Please refer to the Emulator hardware manual about details.

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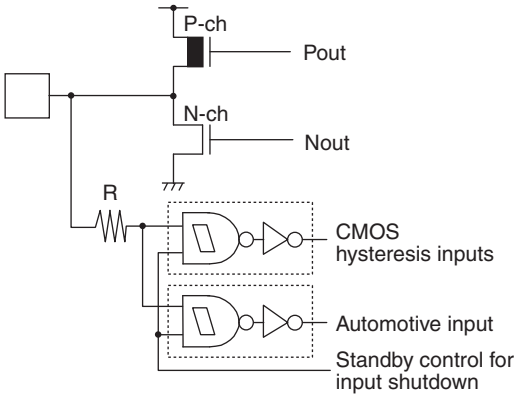
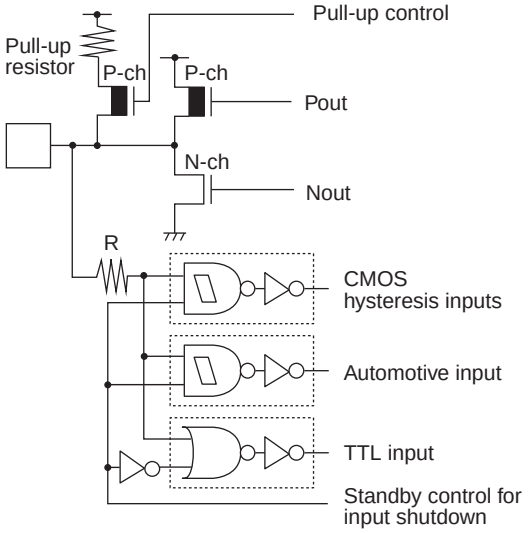
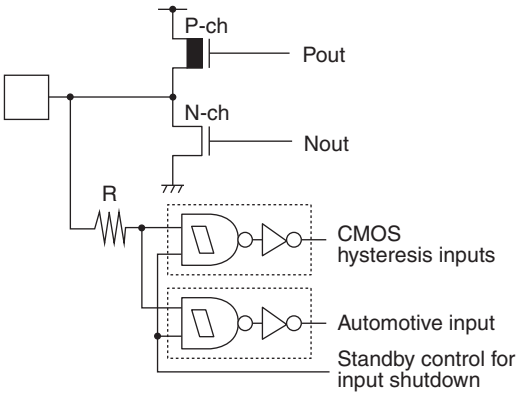
Pin No.	Pin name	I/O Circuit type*	Function
61	P37	G	General purpose I/O port. The register can be set to select whether to use a pull-up resistor. This function is enabled either in single-chip mode or with the CLK output disabled.
	CLK		CLK output pin. This function is enabled when both the external bus and CLK output are enabled.
	OUT7		Wave form output pin for output compare OCU7
62, 63	P60, P61	I	General purpose I/O ports
	AN0, AN1		Analog input pins for A/D converter
64	AV_{CC}	K	V_{CC} power input pin for analog circuits
2	AVRH	L	Reference voltage input for the A/D converter. This power supply must be turned on or off while a voltage higher than or equal to AVRH is applied to AV_{CC}.
1	AV_{SS}	K	V_{SS} power input pin for analog circuits
22, 23	MD1, MD0	C	Input pins for specifying the operating mode
21	MD2	D	Input pin for specifying the operating mode
49	V_{CC}	—	Power (3.5 V to 5.5 V) input pin
18, 48	V_{SS}	—	Power (0 V) input pins
50	C	K	This is the power supply stabilization capacitor pin. It should be connected to a higher than or equal to 0.1 μF ceramic capacitor.

* : For the I/O circuit type, refer to “I/O Circuit Type”.

Type	Circuit	Remarks
F		■ CMOS level output (I_{OL} = 4 mA, I_{OH} = −4 mA) ■ CMOS hysteresis inputs (With input shutdown function when is standby) ■ Automotive input (With the standby-time input shutdown function)
G		■ CMOS level output (I_{OL} = 4 mA, I_{OH} = −4 mA) ■ CMOS hysteresis inputs (With the standby-time input shutdown function) ■ Automotive input (With the standby-time input shutdown function) ■ TTL input (With the standby-time input shutdown function) ■ Programmable pull-up resistor: approx. 50 kΩ
H		■ CMOS level output (I_{OL} = 3 mA, I_{OH} = −3 mA) ■ CMOS hysteresis inputs (With the standby-time input shutdown function) ■ Automotive input (With the standby-time input shutdown function)

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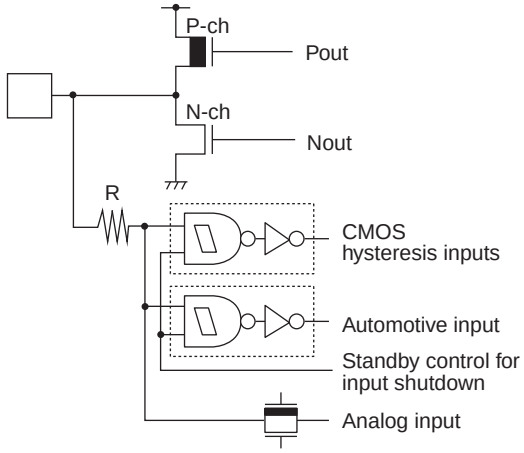
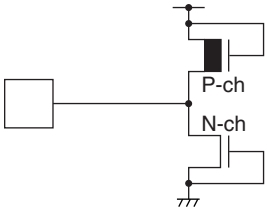
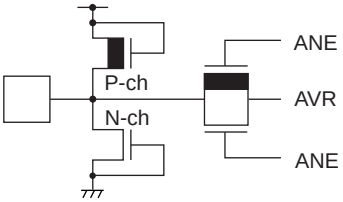
Type	Circuit	Remarks
I		■ CMOS level output (I_{OL} = 4 mA, I_{OH} = −4 mA) ■ CMOS hysteresis inputs (With the standby-time input shutdown function) ■ Automotive input (With the standby-time input shutdown function) ■ Analog input for A/D converter
K		Protection circuit for power supply input
L		■ With the protection circuit of A/D converter reference voltage power input pin ■ Flash memory devices do not have a protection circuit against V_{CC} for pin AVRH.

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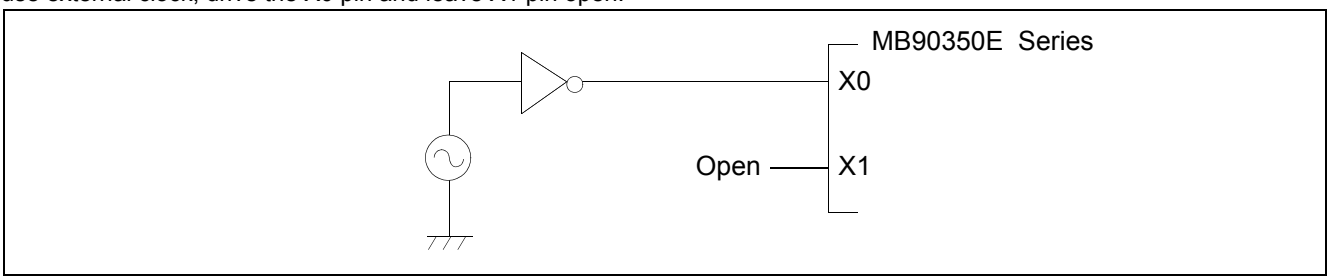
3. Using external clock

To use external clock, drive the X0 pin and leave X1 pin open.



4. Precautions for when not using a sub clock signal

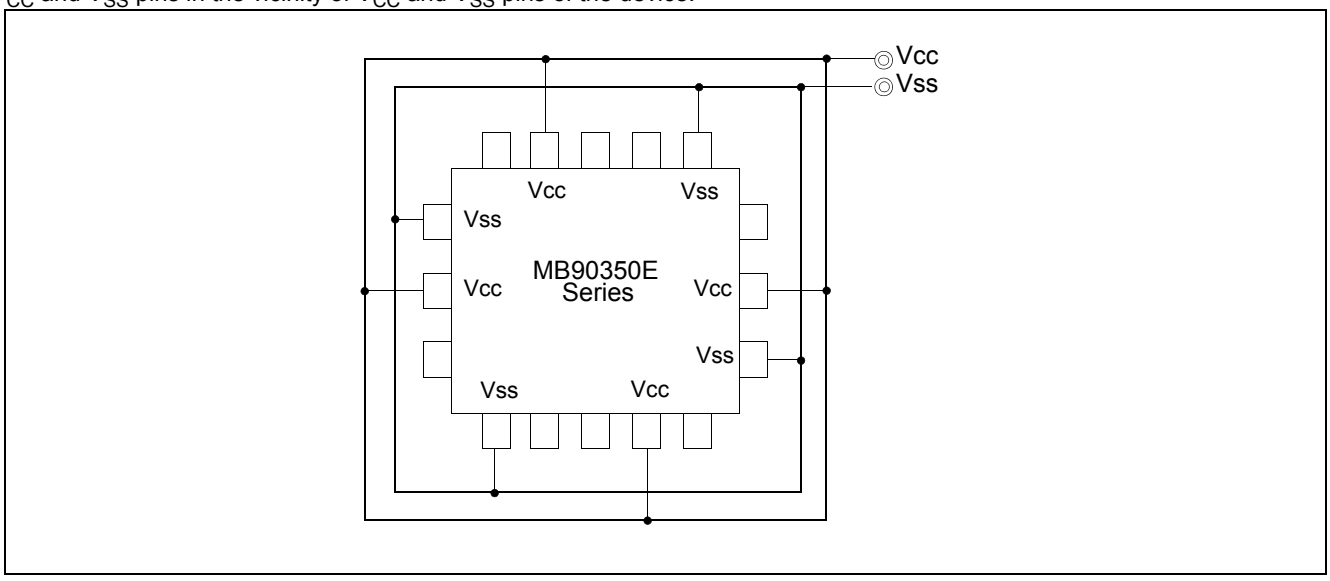
X0A and X1A are oscillation pins for sub clock. If you do not connect pins X0A and X1A to an oscillator, use pull-down handling on the X0A pin, and leave the X1A pin open.

5. Notes on during operation of PLL clock mode

On this microcontroller, if in case the crystal oscillator breaks off or an external reference clock input stops while the PLL clock mode is selected, a self-oscillator circuit contained in the PLL may continue its operation at its self-running frequency. However, Cypress will not guarantee results of operations if such failure occurs.

6. Treatment of Power Supply Pins (V_{CC}/V_{SS})

- If there are multiple V_{CC} and V_{SS} pins, from the point of view of device design, pins to be of the same potential are connected inside of the device to prevent malfunction such as latch-up.
  To reduce unnecessary radiation, prevent malfunctioning of the strobe signal due to the rise of ground level, and observe the standard for total output current, be sure to connect the V_{CC} and V_{SS} pins to the power supply and ground externally.
  Connect V_{CC} and V_{SS} pins to the device from the current supply source at a possibly low impedance.
- As a measure against power supply noise, it is recommended to connect a capacitor of about 0.1 µF as a bypass capacitor between V_{CC} and V_{SS} pins in the vicinity of V_{CC} and V_{SS} pins of the device.



7. Pull-up/down resistors

The MB90350E series does not support internal pull-up/down resistors (Port 0 to Port 3: built-in pull-up resistors). Use external components where needed.

8. Crystal oscillator circuit

Noise around the X0/X1, or X0A/X1A pins may cause this device to operate abnormally. In the interest of stable operation it is strongly recommended that printed circuit artwork places ground bypass capacitors as close as possible to the X0/X1, X0A/X1A and crystal oscillator (or ceramic oscillator) and that oscillator lines do not cross the lines of other circuits.

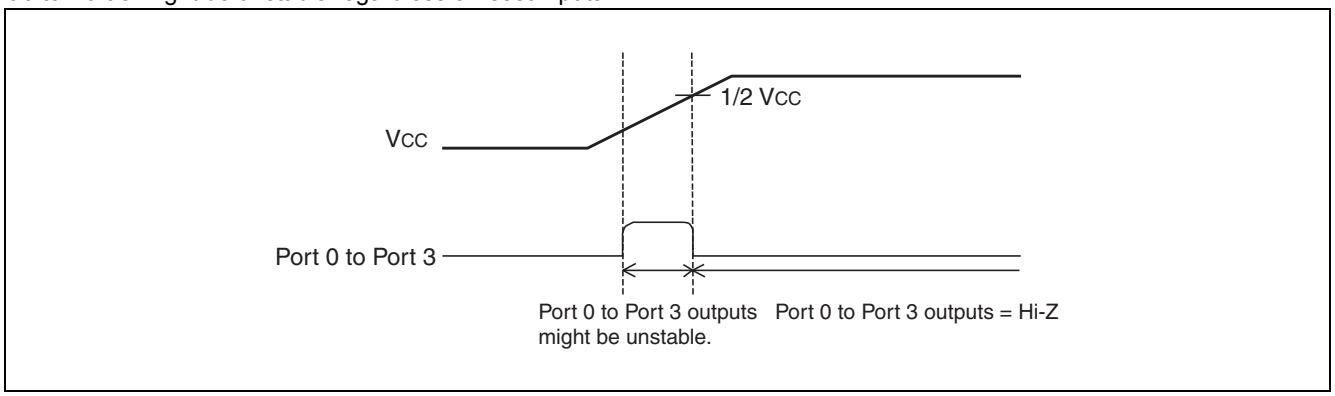
13. Serial Communication

There is a possibility to receive wrong data due to the noise or other causes on the serial communication. Therefore, design a printed circuit board so as to avoid noise.

Retransmit the data if an error occurs because of applying the checksum to the last data in consideration of receiving wrong data due to the noise.

14. Port 0 to port 3 output during power-on (External-bus mode)

As shown below, when power is turned on in external-bus mode, there is a possibility that output signal of Port 0 to Port 3 might be unstable regardless of reset inputs.



15. Setting using CAN function

To use CAN function, please set “1” to DIRECT bit of CAN direct mode register (CDMR).

16. Flash security function

The security byte is located in the area of the Flash memory. If protection code 01_H is written in the security byte, the Flash memory is in the protected state by security.
Therefore please do not write 01_H in this address if you do not use the security function.
Please refer to following table for the address of the security byte.

Product name	Flash memory size	Address for security bit
MB90F352E(S) MB90F352TE(S) MB90F357E(S) MB90F357TE(S)	Embedded 1 Mbit Flash memory	$FE0001_H$

17. Operation with T_A = +105°C or more

If used exceeding $T_A = +105°C$, please contact Cypress sales representatives for reliability limitations.

18. Low voltage/CPU operation reset circuit

The low voltage detection reset circuit is a function that monitors power supply voltage in order to detect when a voltage drops below a given voltage level. When a low voltage condition is detected, an internal reset signal is generated.
The CPU operation detection reset circuit is a 20-bit counter that uses oscillation as a count clock and generates an internal reset signal if not cleared within a given time after startup.

(1) Low voltage detection reset circuit

Detection voltage
4.0 V ± 0.3 V

When a low voltage condition is detected, the low voltage detection flag (LVRC : LVRF) is set to “1” and an internal reset signal is output.
Because the low voltage detection reset circuit continues to operate even in stop mode, detection of a low voltage condition generates an internal reset and releases stop mode.

10. I/O Map

Address	Register	Abbreviation	Access	Resource name	Initial value
000000_H	Port 0 Data Register	PDR0	R/W	Port 0	$XXXXXXXX_B$
000001_H	Port 1 Data Register	PDR1	R/W	Port 1	$XXXXXXXX_B$
000002_H	Port 2 Data Register	PDR2	R/W	Port 2	$XXXXXXXX_B$
000003_H	Port 3 Data Register	PDR3	R/W	Port 3	$XXXXXXXX_B$
000004_H	Port 4 Data Register	PDR4	R/W	Port 4	$XXXXXXXX_B$
000005_H	Port 5 Data Register	PDR5	R/W	Port 5	$XXXXXXXX_B$
000006_H	Port 6 Data Register	PDR6	R/W	Port 6	$XXXXXXXX_B$
000007_H to $00000A_H$	Reserved				
$00000B_H$	Port 5 Analog Input Enable Register	ADER5	R/W	Port 5, A/D	11111111_B
$00000C_H$	Port 6 Analog Input Enable Register	ADER6	R/W	Port 6, A/D	11111111_B
$00000D_H$	Reserved				
$00000E_H$	Input Level Select Register 0	ILSR0	R/W	Ports	00000000_B
$00000F_H$	Input Level Select Register 1	ILSR1	R/W	Ports	00000000_B
000010_H	Port 0 Direction Register	DDR0	R/W	Port 0	00000000_B
000011_H	Port 1 Direction Register	DDR1	R/W	Port 1	00000000_B
000012_H	Port 2 Direction Register	DDR2	R/W	Port 2	$XX000000_B$
000013_H	Port 3 Direction Register	DDR3	R/W	Port 3	00000000_B
000014_H	Port 4 Direction Register	DDR4	R/W	Port 4	$XX000000_B$
000015_H	Port 5 Direction Register	DDR5	R/W	Port 5	$X0000000_B$
000016_H	Port 6 Direction Register	DDR6	R/W	Port 6	00000000_B
000017_H to 000019_H	Reserved				
$00001A_H$	SIN input Level Setting Register	DDRA	W	UART2, UART3	$X00XXXXX_B$
$00001B_H$	Reserved				
$00001C_H$	Port 0 Pull-up Control Register	PUCR0	R/W	Port 0	00000000_B
$00001D_H$	Port 1 Pull-up Control Register	PUCR1	R/W	Port 1	00000000_B
$00001E_H$	Port 2 Pull-up Control Register	PUCR2	R/W	Port 2	00000000_B
$00001F_H$	Port 3 Pull-up Control Register	PUCR3	R/W	Port 3	00000000_B
000020_H to 000037_H	Reserved				

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Address	Register	Abbreviation	Access	Resource name	Initial value
$00009B_H$	DMA Descriptor Channel Specification Register	DCSR	R/W	DMA	00000000_B
$00009C_H$	DMA Status Register L Register	DSRL	R/W		00000000_B
$00009D_H$	DMA Status Register H Register	DSRH	R/W		00000000_B
$00009E_H$	Address Detect Control Register 0	PACSR0	R/W	Address Match Detection 0	00000000_B
$00009F_H$	Delayed Interrupt/Release Register	DIRR	R/W	Delayed Interrupt	$XXXXXXX0_B$
$0000A0_H$	Low-power Consumption Mode Control Register	LPMCR	W,R/W	Low Power Consumption Control Circuit	00011000_B
$0000A1_H$	Clock Selection Register	CKSCR	R,R/W	Low Power Consumption Control Circuit	11111100_B
$0000A2_H$, $0000A3_H$	Reserved				
$0000A4_H$	DMA Stop Status Register	DSSR	R/W	DMA	00000000_B
$0000A5_H$	Automatic Ready Function Selection Register	ARSR	W	External Memory Access	$0011XX00_B$
$0000A6_H$	External Address Output Control Register	HACR	W		00000000_B
$0000A7_H$	Bus Control Signal Selection Register	ECSR	W		$0000000X_B$
$0000A8_H$	Watchdog Control Register	WDTC	R,W	Watchdog Timer	$XXXXX111_B$
$0000A9_H$	Timebase Timer Control Register	TBTC	W,R/W	Timebase timer	$1XX00100_B$
$0000AA_H$	Watch Timer Control Register	WTC	R,R/W	Watch Timer	$1X001000_B$
$0000AB_H$	Reserved				
$0000AC_H$	DMA Enable Register L Register	DERL	R/W	DMA	00000000_B
$0000AD_H$	DMA Enable Register H Register	DERH	R/W		00000000_B
$0000AE_H$	Flash Control Status Register (Flash Devices only. Otherwise reserved)	FMCS	R,R/W	Flash memory	$000X0000_B$
$0000AF_H$	Reserved				
$0000B0_H$	Interrupt Control Register 00	ICR00	W,R/W	Interrupt Control	00000111_B
$0000B1_H$	Interrupt Control Register 01	ICR01	W,R/W		00000111_B
$0000B2_H$	Interrupt Control Register 02	ICR02	W,R/W		00000111_B
$0000B3_H$	Interrupt Control Register 03	ICR03	W,R/W		00000111_B
$0000B4_H$	Interrupt Control Register 04	ICR04	W,R/W		00000111_B
$0000B5_H$	Interrupt Control Register 05	ICR05	W,R/W		00000111_B
$0000B6_H$	Interrupt Control Register 06	ICR06	W,R/W		00000111_B
$0000B7_H$	Interrupt Control Register 07	ICR07	W,R/W		00000111_B
$0000B8_H$	Interrupt Control Register 08	ICR08	W,R/W		00000111_B

(Continued)

Address	Register	Abbreviation	Access	Resource name	Initial value
007950_H	Serial Mode Register 3	SMR3	W, R/W	UART3	00000000_B
007951_H	Serial Control Register 3	SCR3	W, R/W		00000000_B
007952_H	Reception/Transmission Data Register 3	RDR3/TDR3	R/W		00000000_B
007953_H	Serial Status Register 3	SSR3	R,R/W		00001000_B
007954_H	Extended Communication Control Register 3	ECCR3	R,W, R/W		$000000XX_B$
007955_H	Extended Status Control Register 3	ESCR3	R/W		00000100_B
007956_H	Baud Rate Generator Register 30	BGR30	R/W		00000000_B
007957_H	Baud Rate Generator Register 31	BGR31	R/W		00000000_B
007958_H, 007959_H	Reserved				
007960_H	Clock supervisor Control Register	CSVCR	R, R/W	Clock Supervisor	00011100_B
007961_H to $00796D_H$	Reserved				
$00796E_H$	CAN Direct Mode Register	CDMR	R/W	CAN Clock Sync	$XXXXXXX0_B$
$00796F_H$	Reserved				
007970_H	I^2C Bus Status Register 0	IBSR0	R	I^2C Interface 0	00000000_B
007971_H	I^2C Bus Control Register 0	IBCR0	W,R/W		00000000_B
007972_H	I^2C 10-bit Slave Address Register 0	ITBAL0	R/W		00000000_B
007973_H		ITBAH0	R/W		00000000_B
007974_H	I^2C 10-bit Slave Address Mask Register 0	ITMKL0	R/W		11111111_B
007975_H		ITMKH0	R/W		00111111_B
007976_H	I^2C 7-bit Slave Address Register 0	ISBA0	R/W		00000000_B
007977_H	I^2C 7-bit Slave Address Mask Register 0	ISMK0	R/W		01111111_B
007978_H	I^2C data register 0	IDAR0	R/W		00000000_B
007979_H, $00797A_H$	Reserved				
$00797B_H$	I^2C Clock Control Register 0	ICCR0	R/W	I^2C Interface 0	00011111_B
$00797C_H$ to $0079A1_H$	Reserved				
$0079A2_H$	Flash Write Control Register 0	FWR0	R/W	Dual Operation Flash	00000000_B
$0079A3_H$	Flash Write Control Register 1	FWR1	R/W		00000000_B
$0079A4_H$	Sector Change Setting Register 0	SSR0	R/W		$00XXXXX0_B$
$0079A5_H$ to $0079C1_H$	Reserved				
$0079C2_H$	Clock modulator Control Register	CMCR	R, R/W	Clock Modulator	$0001X000_B$

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Address	Register	Abbreviation	Access	Resource name	Initial value
$0079C3_H$ to $0079DF_H$	Reserved				
$0079E0_H$	Detect Address Setting Register 0	PADR0	R/W	Address Match Detection 0	$XXXXXXXX_B$
$0079E1_H$	Detect Address Setting Register 0	PADR0	R/W		$XXXXXXXX_B$
$0079E2_H$	Detect Address Setting Register 0	PADR0	R/W		$XXXXXXXX_B$
$0079E3_H$	Detect Address Setting Register 1	PADR1	R/W		$XXXXXXXX_B$
$0079E4_H$	Detect Address Setting Register 1	PADR1	R/W		$XXXXXXXX_B$
$0079E5_H$	Detect Address Setting Register 1	PADR1	R/W		$XXXXXXXX_B$
$0079E6_H$	Detect Address Setting Register 2	PADR2	R/W		$XXXXXXXX_B$
$0079E7_H$	Detect Address Setting Register 2	PADR2	R/W		$XXXXXXXX_B$
$0079E8_H$	Detect Address Setting Register 2	PADR2	R/W		$XXXXXXXX_B$
$0079E9_H$ to $0079EF_H$	Reserved				
$0079F0_H$	Detect Address Setting Register 3	PADR3	R/W	Address Match Detection 1	$XXXXXXXX_B$
$0079F1_H$	Detect Address Setting Register 3	PADR3	R/W		$XXXXXXXX_B$
$0079F2_H$	Detect Address Setting Register 3	PADR3	R/W		$XXXXXXXX_B$
$0079F3_H$	Detect Address Setting Register 4	PADR4	R/W		$XXXXXXXX_B$
$0079F4_H$	Detect Address Setting Register 4	PADR4	R/W		$XXXXXXXX_B$
$0079F5_H$	Detect Address Setting Register 4	PADR4	R/W		$XXXXXXXX_B$
$0079F6_H$	Detect Address Setting Register 5	PADR5	R/W		$XXXXXXXX_B$
$0079F7_H$	Detect Address Setting Register 5	PADR5	R/W		$XXXXXXXX_B$
$0079F8_H$	Detect Address Setting Register 5	PADR5	R/W		$XXXXXXXX_B$
$0079F9_H$ to $007BFF_H$	Reserved				
$007C00_H$ to $007DFF_H$	Reserved for CAN controller 1. Refer to “CAN Controllers”				
$007E00_H$ to $007FFF_H$	Reserved				

Notes : ″ Initial value of “X” represents unknown value.
″ Any write access to reserved addresses in I/O map should not be performed. A read access to reserved addresses results reading unknown value.

11. CAN Controllers

■ Compliant with CAN standard Version2.0 Part A and Part B
- Supports tr12ansmission/reception in standard frame and extended frame formats

■ Supports transmitting of data frames by receiving remote frames

■ 16 transmitting/receiving message buffers
- 29-bit ID and 8-byte data
- Multi-level message buffer configuration

■ Provides full-bit comparison, full-bit mask, acceptance register 0/acceptance register 1 for each message buffer as ID acceptance mask
- Two acceptance mask registers in either standard frame format or extended frame formats

■ Bit rate programmable from 10 kbps to 2 Mbps (when input clock is at 16 MHz)

List of Message Buffers (DLC Registers and Data Registers)

Address CAN1	Register	Abbreviation	Access	Initial Value
$007C60_H$	DLC register 0	DLCR0	R/W	$XXXXXXXX_B$
$007C61_H$				
$007C62_H$	DLC register 1	DLCR1	R/W	$XXXXXXXX_B$
$007C63_H$				
$007C64_H$	DLC register 2	DLCR2	R/W	$XXXXXXXX_B$
$007C65_H$				
$007C66_H$	DLC register 3	DLCR3	R/W	$XXXXXXXX_B$
$007C67_H$				
$007C68_H$	DLC register 4	DLCR4	R/W	$XXXXXXXX_B$
$007C69_H$				
$007C6A_H$	DLC register 5	DLCR5	R/W	$XXXXXXXX_B$
$007C6B_H$				
$007C6C_H$	DLC register 6	DLCR6	R/W	$XXXXXXXX_B$
$007C6D_H$				
$007C6E_H$	DLC register 7	DLCR7	R/W	$XXXXXXXX_B$
$007C6F_H$				
$007C70_H$	DLC register 8	DLCR8	R/W	$XXXXXXXX_B$
$007C71_H$				
$007C72_H$	DLC register 9	DLCR9	R/W	$XXXXXXXX_B$
$007C73_H$				
$007C74_H$	DLC register 10	DLCR10	R/W	$XXXXXXXX_B$
$007C75_H$				
$007C76_H$	DLC register 11	DLCR11	R/W	$XXXXXXXX_B$
$007C77_H$				
$007C78_H$	DLC register 12	DLCR12	R/W	$XXXXXXXX_B$
$007C79_H$				
$007C7A_H$	DLC register 13	DLCR13	R/W	$XXXXXXXX_B$
$007C7B_H$				
$007C7C_H$	DLC register 14	DLCR14	R/W	$XXXXXXXX_B$
$007C7D_H$				
$007C7E_H$	DLC register 15	DLCR15	R/W	$XXXXXXXX_B$
$007C7F_H$				

(Continued)

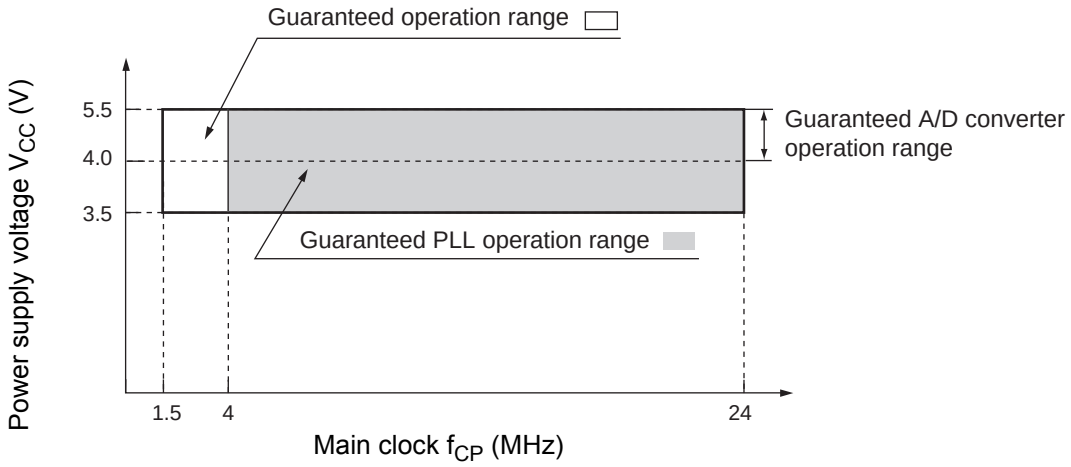
13.3 DC Characteristics

(T_A = −40°C to +125°C, V_{CC} = 5.0 V ± 10%, f_{CP} ≤ 24 MHz, V_{SS} = AV_{SS} = 0 V)

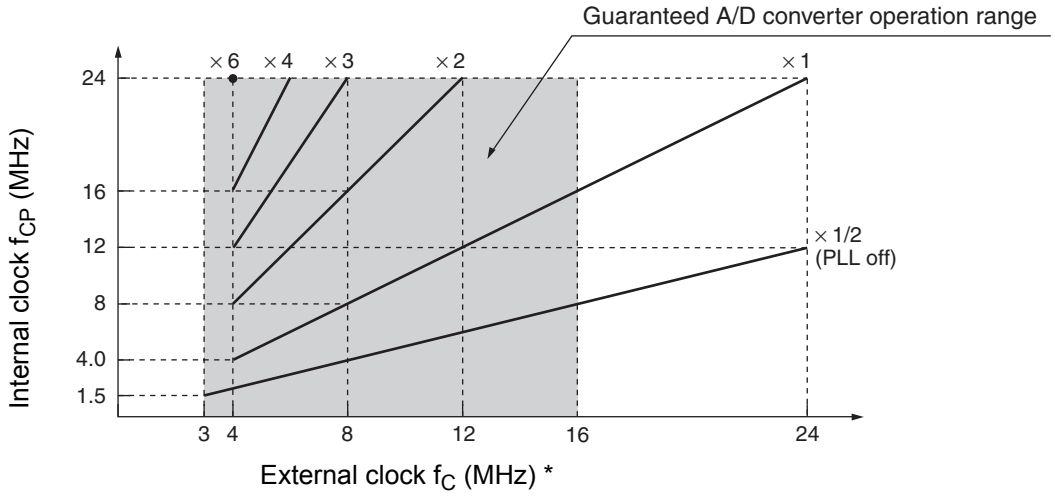
Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min	Typ	Max		
"H" level input voltage (At V_{CC} = 5 V ± 10%)	V_{IHS}	—	—	0.8 V_{CC}	—	V_{CC} + 0.3	V	Pin inputs if CMOS hysteresis input levels are selected (except P12, P15, P44, P45, P50)
	V_{IHA}	—	—	0.8 V_{CC}	—	V_{CC} + 0.3	V	Pin inputs if Automotive input levels are selected
	V_{IHT}	—	—	2.0	—	V_{CC} + 0.3	V	Pin inputs if TTL input levels are selected
	V_{IHS}	—	—	0.7 V_{CC}	—	V_{CC} + 0.3	V	P12, P15, P50 inputs if CMOS input levels are selected
	V_{IHI}	—	—	0.7 V_{CC}	—	V_{CC} + 0.3	V	P44, P45 inputs if CMOS hysteresis input levels are selected
	V_{IHR}	—	—	0.8 V_{CC}	—	V_{CC} + 0.3	V	$\overline{RST}$ input pin (CMOS hysteresis)
	V_{IHM}	—	—	V_{CC} − 0.3	—	V_{CC} + 0.3	V	MD input pin
"L" level input voltage (At V_{CC} = 5 V ± 10%)	V_{ILS}	—	—	V_{SS} − 0.3	—	0.2 V_{CC}	V	Pin inputs if CMOS hysteresis input levels are selected (except P12, P15, P44, P45, P50)
	V_{ILA}	—	—	V_{SS} − 0.3	—	0.5 V_{CC}	V	Pin inputs if Automotive input levels are selected
	V_{ILT}	—	—	V_{SS} − 0.3	—	0.8	V	Pin inputs if TTL input levels are selected
	V_{ILS}	—	—	V_{SS} − 0.3	—	0.3 V_{CC}	V	P12, P15, P50 inputs if CMOS input levels are selected
	V_{ILI}	—	—	V_{SS} − 0.3	—	0.3 V_{CC}	V	P44, P45 inputs if CMOS hysteresis input levels are selected
	V_{ILR}	—	—	V_{SS} − 0.3	—	0.2 V_{CC}	V	$\overline{RST}$ input pin (CMOS hysteresis)
	V_{ILM}	—	—	V_{SS} − 0.3	—	V_{SS} + 0.3	V	MD input pin
Output "H" voltage	V_{OH}	Normal outputs	V_{CC} = 4.5 V, I_{OH} = −4.0 mA	V_{CC} − 0.5	—	—	V	
Output "H" voltage	V_{OHI}	I^2C current outputs	V_{CC} = 4.5 V, I_{OH} = −3.0 mA	V_{CC} − 0.5	—	—	V	

(Continued)

• PLL guaranteed operation range



Guaranteed operation range of MB90350E series



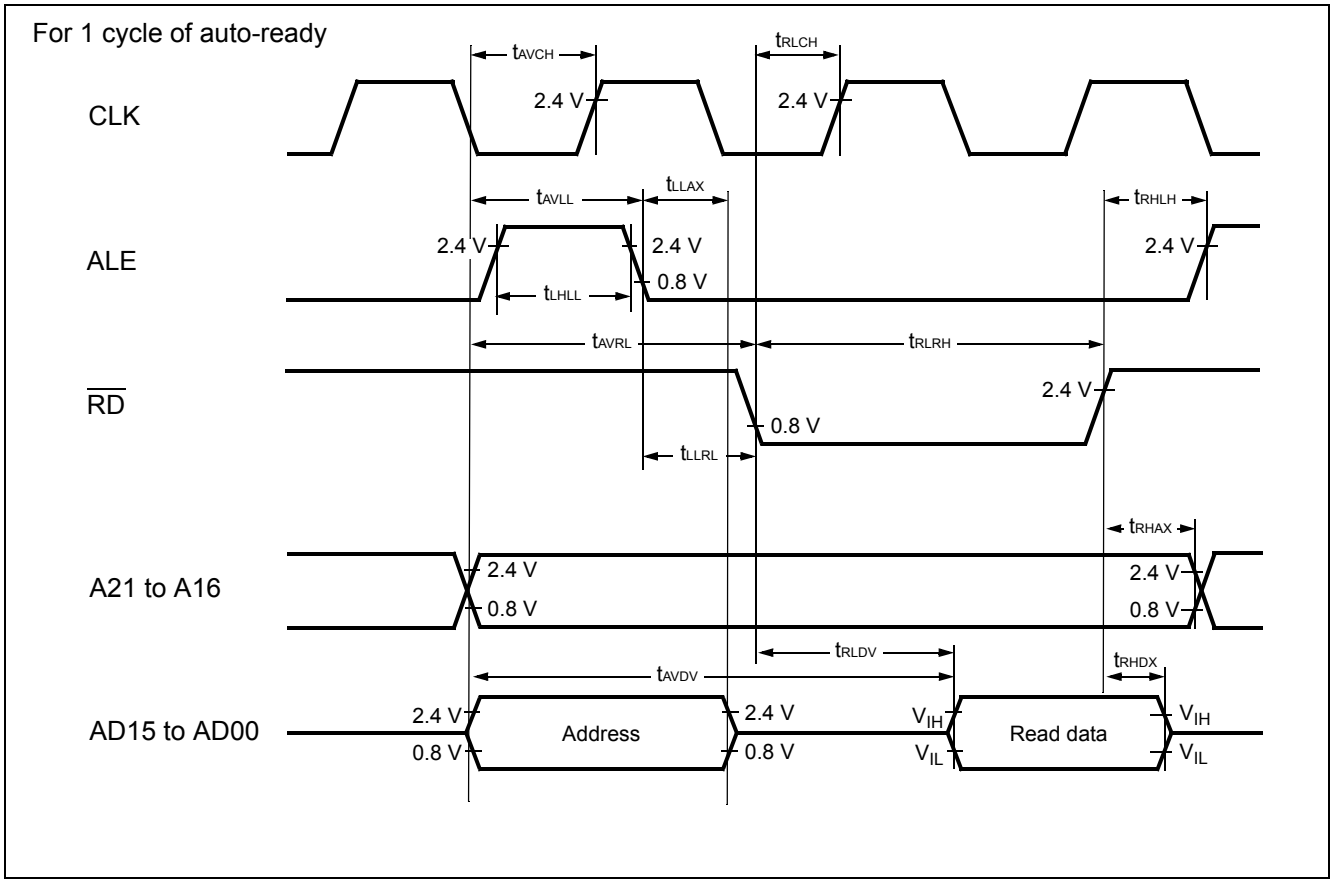
* : When using crystal oscillator or ceramic oscillator, the maximum clock frequency is 16 MHz.

External clock frequency and internal operation clock frequency

13.4.2 Reset Standby Input

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, f_{CP} ≤ 24 MHz, V_{SS} = AV_{SS} = 0 V)

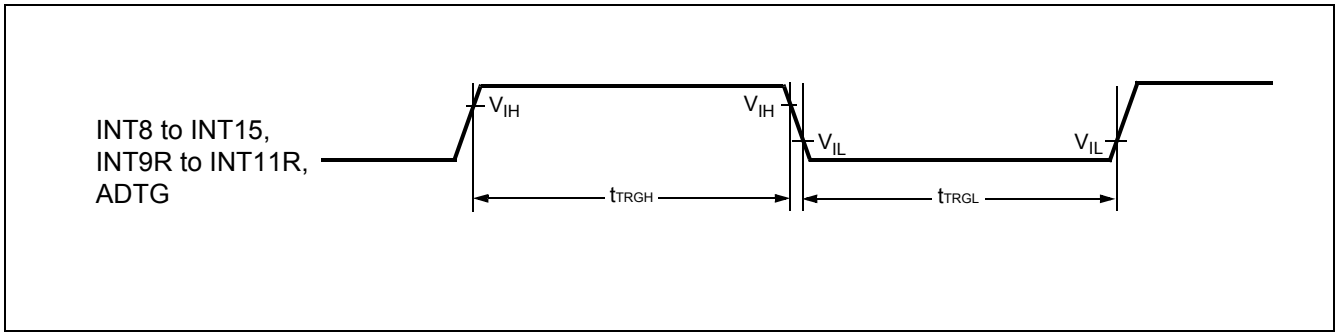
Parameter	Symbol	Pin	Value		Unit	Remarks
			Min	Max		
Reset input time	t_{RSTL}	$\overline{RST}$	500	–	ns	Under normal operation
			Oscillation time of oscillator* + 100 µs	–	µs	In Stop mode, Sub Clock mode, Sub Sleep mode and Watch mode
			100	–	µs	In Main timer mode and PLL timer mode


For 1 cycle of auto-ready
CLK
ALE
RD
A21 to A16
AD15 to AD00
tAVCH
tRLCH
2.4 V
tAVLL
tLLAX
tRHLH
0.8 V
tLHLL
tAVRL
tRLRH
tLLRL
tRHAX
tRLDV
tAVDV
tRHDX
Address
Read data
VIH
VIL

13.4.10 Trigger Input Timing

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, f_{CP} ≤ 24 MHz, V_{SS} = AV_{SS} = 0 V)

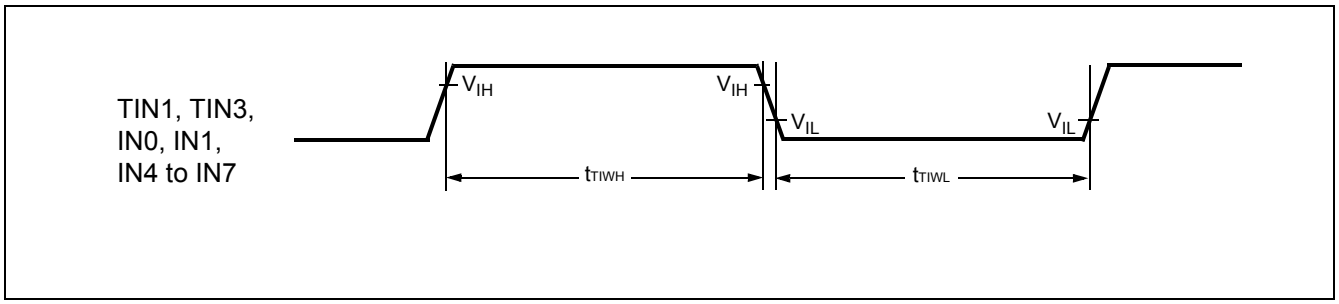
Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
Input pulse width	t_{TRGH} t_{TRGL}	INT8 to INT15, INT9R to INT11R, ADTG	—	5 t_{CP}	—	ns



13.4.11 Timer Related Resource Input Timing

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, f_{CP} ≤ 24 MHz, V_{SS} = AV_{SS} = 0 V)

Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
Input pulse width	t_{TIWH} t_{TIWL}	TIN1, TIN3,IN0, IN1, IN4 to IN7	—	4 t_{CP}	—	ns

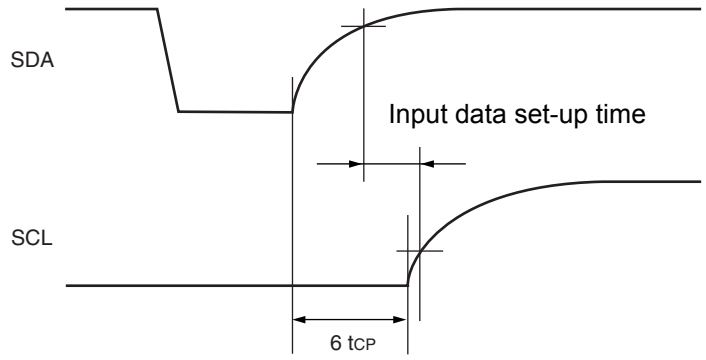


13.4.12 Timer Related Resource Output Timing

(T_A = –40°C to +125°C, V_{CC} = 5.0 V ± 10%, f_{CP} ≤ 24 MHz, V_{SS} = AV_{SS} = 0 V)

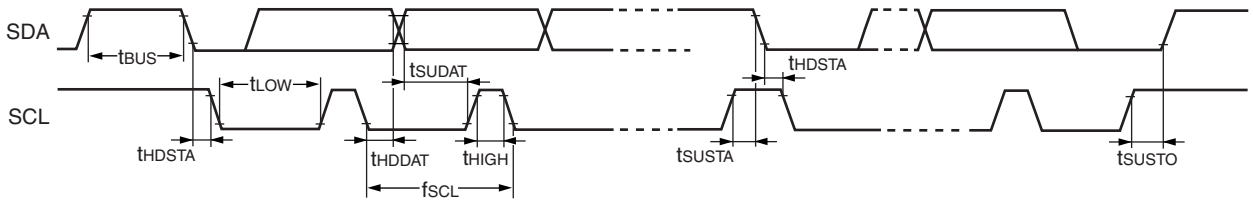
Parameter	Symbol	Pin	Condition	Value		Unit
				Min	Max	
CLK ↑ → T_{OUT} change time	t_{TO}	TOT1, TOT3, PPG4, PPG6, PPG8 to PPGF	—	30	—	ns

• Note of SDA, SCL set-up time



Note : The rating of the input data set-up time in the device connected to the bus cannot be satisfied depending on the load capacitance or pull-up resistor.
Be sure to adjust the pull-up resistor of SDA and SCL if the rating of the input data set-up time cannot be satisfied.

• Timing definition



13.5 A/D Converter

(T_A = −40°C to +125°C, 3.0 V ≤ AVRH, V_{CC} = AV_{CC} = 5.0 V ± 10%, f_{CP} ≤ 24 MHz, V_{SS} = AV_{SS} = 0 V)

Parameter	Symbol	Pin	Value			Unit	Remarks
			Min	Typ	Max		
Resolution	—	—	—	—	10	bit	
Total error	—	—	—	—	±3.0	LSB	
Nonlinearity error	—	—	—	—	±2.5	LSB	
Differential nonlinearity error	—	—	—	—	±1.9	LSB	
Zero reading voltage	V_{OT}	AN0 to AN14	AV_{SS} − 1.5×LSB	AV_{SS} + 0.5×LSB	AV_{SS} + 2.5×LSB	V	
Full scale reading voltage	V_{FST}	AN0 to AN14	AVRH − 3.5×LSB	AVRH − 1.5×LSB	AVRH + 0.5×LSB	V	
Compare time	—	—	1.0	—	16500	µs	4.5 V ≤ AV_{CC} ≤ 5.5 V
			2.0				4.0 V ≤ AV_{CC} < 4.5 V
Sampling time	—	—	0.5	—	×	µs	4.5 V ≤ AV_{CC} ≤ 5.5 V
			1.2				4.0 V ≤ AV_{CC} < 4.5 V
Analog port input current	I_{AIN}	AN0 to AN14	− 0.3	—	+ 0.3	µA	
Analog input voltage range	V_{AIN}	AN0 to AN14	AV_{SS}	—	AVRH	V	
Reference voltage range	—	AVRH	AV_{SS} + 2.7	—	AV_{CC}	V	
Power supply current	I_A	AV_{CC}	—	3.5	7.5	mA	
	I_{AH}	AV_{CC}	—	—	5	µA	*
Reference voltage supply current	I_R	AVRH	—	600	900	µA	
	I_{RH}	AVRH	—	—	5	µA	*
Offset between channels	—	AN0 to AN14	—	—	4	LSB	

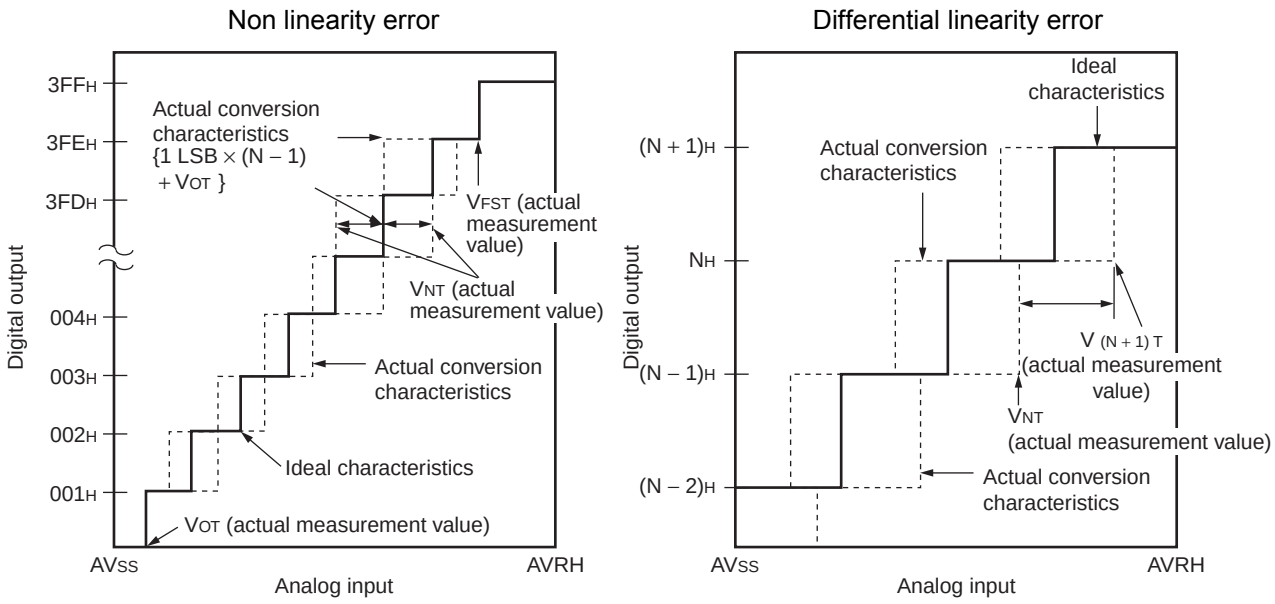
* : If A/D converter is not operating, a current when CPU is stopped is applicable (V_{CC} = AV_{CC} = AVRH = 5.0 V) .

Notes on A/D Converter Section

■ About the external impedance of the analog input and its sampling time

A/D converter with sample and hold circuit. If the external impedance is too high to keep sufficient sampling time, the analog voltage charged to the internal sample and hold capacitor is insufficient, adversely affecting
A/D conversion precision. Therefore to satisfy the A/D conversion precision standard, consider the relationship between the external impedance and minimum sampling time and either adjust the register value and operating frequency or decrease the external impedance so that the sampling time is longer than the minimum value. Also if the sampling time cannot be sufficient, connect a capacitor of about 0.1 µF to the analog input pin.

(Continued)



$$\text{Non linearity error of digital output N} = \frac{V_{NT} - \{1\ \text{LSB} \times (N - 1) + V_{OT}\}}{1\ \text{LSB}}\ \text{[LSB]}$$

$$\text{Differential linearity error of digital output N} = \frac{V_{(N+1)T} - V_{NT}}{1\ \text{LSB}} - 1\ \text{LSB [LSB]}$$

$$1\ \text{LSB} = \frac{V_{FST} - V_{OT}}{1022}\ \text{[V]}$$

N : A/D converter digital output value
V_{OT} : Voltage at which digital output transits from "000_H" to "001_H".
V_{FST} : Voltage at which digital output transits from "$3FE_H$" to "$3FF_H$".

13.7 Flash Memory Program/Erase Characteristics

■ Dual Operation Flash Memory

Parameter	Conditions	Value			Unit	Remarks
		Min	Typ	Max		
Sector erase time (4 Kbytes sector)	T_A = +25°C V_{CC} = 5.0 V	—	0.2	0.5	s	Excludes programming prior to erasure
Sector erase time (16 Kbytes sector)		—	0.5	7.5	s	Excludes programming prior to erasure
Chip erase time		—	4.6	—	s	Excludes programming prior to erasure
Word (16-bit width) programming time		—	64	3600	µs	Except for the overhead time of the system level
Program/Erase cycle	—	10000	—	—	cycle	

Parameter	Conditions	Value			Unit	Remarks
		Min	Typ	Max		
Flash memory Data Retention Time	Average T_A = +85°C	20	—	—	year	*

* : Corresponding value comes from the technology reliability evaluation result.
(Using Arrhenius equation to translate high temperature measurements test result into normalized value at +85°C)

14. Ordering Information

Part number	Package	Remarks
MB90F351EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	Flash memory products (64 Kbytes)
MB90F351ESPMC		
MB90F351TEPMC		
MB90F351TESPMC		
MB90F356EPMC		
MB90F356ESPMC		
MB90F356TEPMC		
MB90F356TESPMC		
MB90F352EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	Dual operation Flash memory products (128 Kbytes)
MB90F352ESPMC		
MB90F352TEPMC		
MB90F352TESPMC		
MB90F357EPMC		
MB90F357ESPMC		
MB90F357TEPMC		
MB90F357TESPMC		
MB90351EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	MASK ROM products (64 Kbytes)
MB90351ESPMC		
MB90351TEPMC		
MB90351TESPMC		
MB90356EPMC		
MB90356ESPMC		
MB90356TEPMC		
MB90356TESPMC		
MB90352EPMC	64-pin plastic LQFP FPT-64P-M23 12.0 mm □, 0.65 mm pitch	MASK ROM products (128 Kbytes)
MB90352ESPMC		
MB90352TEPMC		
MB90352TESPMC		
MB90357EPMC		
MB90357ESPMC		
MB90357TEPMC		
MB90357TESPMC		

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